

SILICON POWER TRANSISTOR 2SC3569

NPN SILICON TRIPLE DIFFUSED TRANSISTOR FOR HIGH-VOLTAGE HIGH-SPEED SWITCHING

The 2SC3569 is a mold power transistor developed for high-voltage high-speed switching, and is ideal for use in drivers such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

FEATURES

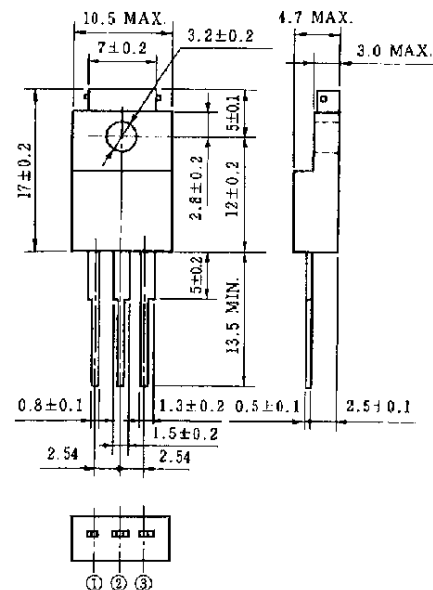
- Mold package that does not require an insulating board or insulation bushing
- Low collector saturation voltage:
 $V_{CE(sat)} = 1.0 \text{ V MAX. (@ } 0.7 \text{ A)}$
- Fast switching speed:
 $t_f \leq 1.0 \mu\text{s MAX. (@ } 0.7 \text{ A)}$
- Wide base reverse-bias SOA:
 $V_{CEX(SUS)} = 450 \text{ V MIN. (@ } 0.5 \text{ A)}$

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	500	V
Collector to emitter voltage	V_{CEO}	400	V
Emitter to base voltage	V_{EBO}	7.0	V
Collector current (DC)	$I_{C(DC)}$	2.0	A
Collector current (pulse)	$I_{C(pulse)}^*$	4.0	A
Base current (DC)	$I_{B(DC)}$	1.0	A
Total power dissipation	$P_T (T_c = 25^\circ\text{C})$	15	W
Total power dissipation	$P_T (T_a = 25^\circ\text{C})$	2.0	W
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

* $PW \leq 300 \mu\text{s}$, duty cycle $\leq 10\%$

PACKAGE DRAWING (UNIT: mm)



Electrode Connection

1. Base
2. Collector
3. Emitter

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

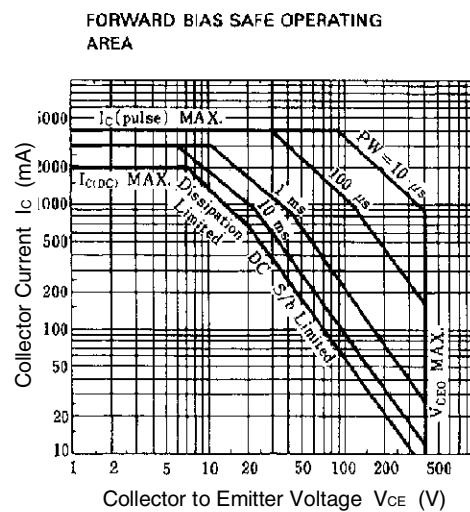
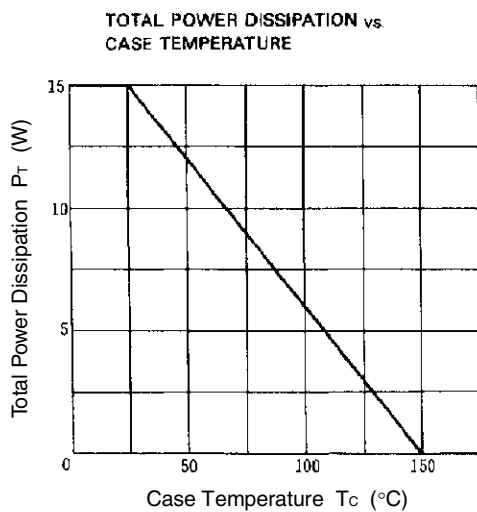
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	V _{CE0(SUS)}	I _C = 0.5 A, I _{B1} = 0.1 A, L = 1 mH	400			V
Collector to emitter voltage	V _{CEX(SUS)1}	I _C = 0.5 A, I _{B1} = -I _{B2} = 0.1 A, L = 180 μH, clamped	450			V
Collector to emitter voltage	V _{CEX(SUS)2}	I _C = 1.0 A, I _{B1} = 0.2 A, -I _{B2} = 0.1 A, L = 180 μH, clamped	400			V
Collector cutoff current	I _{CBO}	V _{CB} = 400 V, I _E = 0			10	μA
Collector cutoff current	I _{CER}	V _{CE} = 400 V, R _{BE} = 51 Ω, Ta = 125°C			1.0	mA
Collector cutoff current	I _{CX1}	V _{CE} = 400 V, V _{BE(OFF)} = -1.5 V			10	μA
Collector cutoff current	I _{CX2}	V _{CE} = 400 V, V _{BE(OFF)} = -1.5 V, Ta = 125°C			1.0	mA
Emitter cutoff current	I _{EBO}	V _{EB} = 5.0 V, I _C = 0			10	μA
DC current gain	h _{FE1} *	V _{CE} = 5.0 V, I _C = 0.2 A	20		80	
DC current gain	h _{FE2} *	V _{CE} = 5.0 V, I _C = 0.5 A	10			
Collector saturation voltage	V _{CE(sat)} *	I _C = 0.7 A, I _B = 0.14 A			1.0	V
Base saturation voltage	V _{BE(sat)} *	I _C = 0.7 A, I _B = 0.14 A			1.2	V
Turn-on time	t _{on}	I _C = 0.7 A, R _L = 214 Ω, I _{B1} = -I _{B2} = 0.14 A, V _{CC} ≡ 150 V			1.0	μs
Storage time	t _{stg}	Refer to the test circuit.			2.5	μs
Fall time	t _f				1.0	μs

* Pulse test PW ≤ 350 μs, duty cycle ≤ 2%

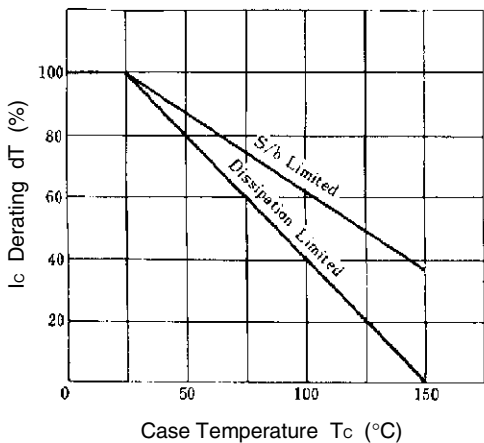
h_{FE} CLASSIFICATION

Marking	M	L	K
H _{FE1}	20 to 40	30 to 60	40 to 80

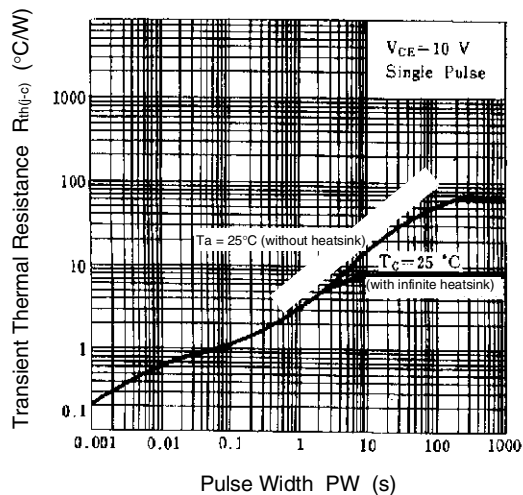
TYPICAL CHARACTERISTICS (Ta = 25°C)



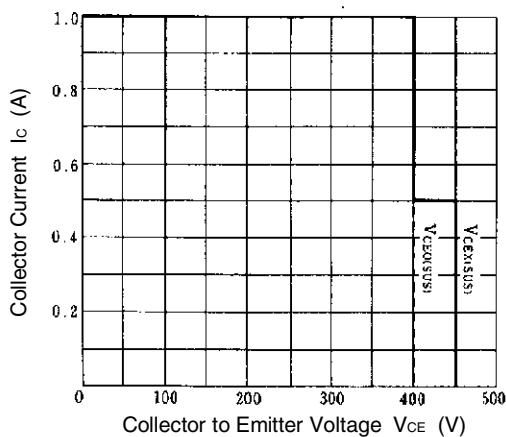
DERATING CURVE OF SAFE OPERATING AREA



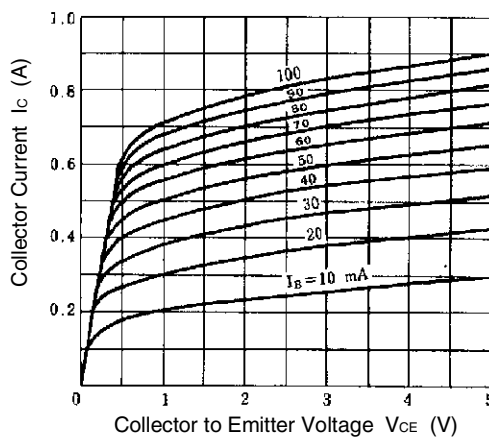
TRANSIENT THERMAL RESISTANCE



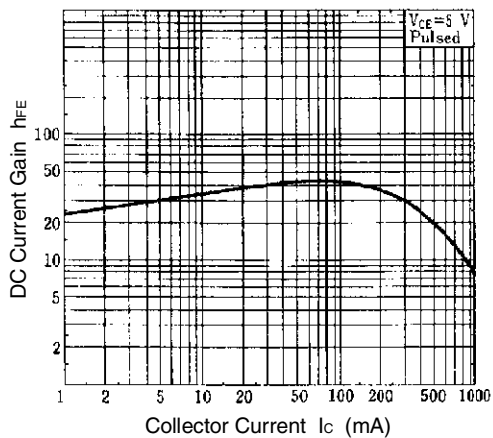
REVERSE BIAS SAFE OPERATING AREA



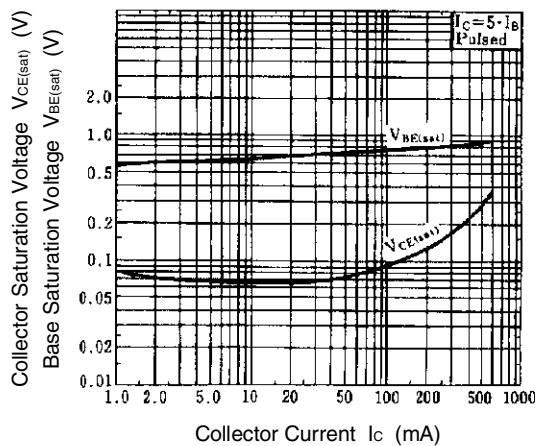
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



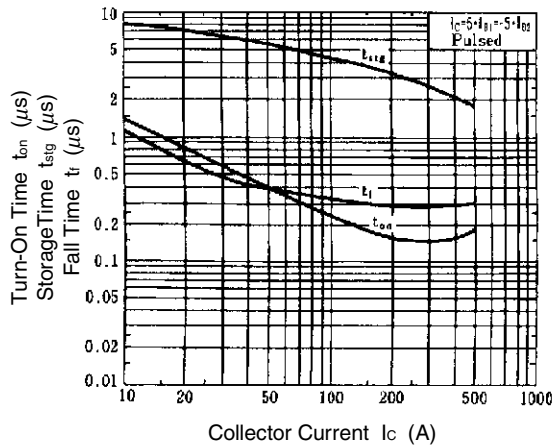
DC CURRENT GAIN vs. COLLECTOR CURRENT



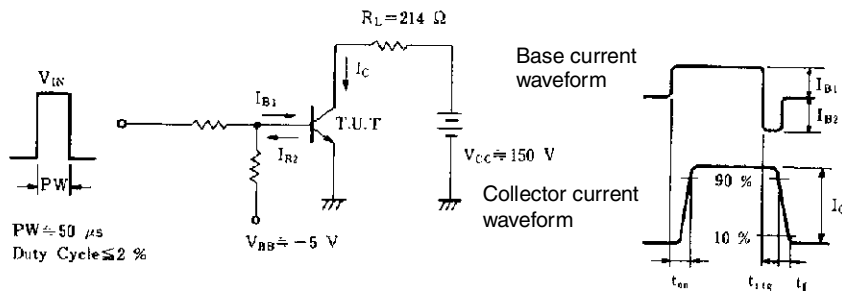
BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



TURN ON TIME, STORAGE TIME AND FALL TIME vs. COLLECTOR CURRENT



SWITCHING TIME (t_{on}, t_{stg}, t_f) TEST CIRCUIT



[MEMO]

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